



### Red SND 3660/3667R (GaP)

#### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Power dissipation/Total	1920	mW
Power dissipation/Seg	40	mW
Forward current	20	mA
Peak forward current	60*	mA
Reverse voltage	4	V
Operating temperature	- 25 ~ + 85	°C
Storage temperature	- 55 ~ + 100	°C

#### Electrical/Optical Characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Min	Typ	Max.	Unit
Forward voltage/Seg	V <sub>F</sub>	I <sub>F</sub> = 10mA	—	2.1	2.3	V
Reverse current /Seg	I <sub>R</sub>	V <sub>R</sub> = 4V	—	—	10	μA
Luminous Intensity/digit	I <sub>V</sub>	I <sub>F</sub> = 10mA	300	800	—	μcd
Peak wavelength	λ <sub>P</sub>	I <sub>F</sub> = 10mA	—	700	—	nm
Spectral line halfwidth	Δλ	I <sub>F</sub> = 10mA	—	100	—	nm

### Green SND 3660/3667G (GaP)

#### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Power dissipation/Total	1920	mW
Power dissipation/Seg	40	mW
Forward current	20	mA
Peak forward current	60*	mA
Reverse voltage	4	V
Operating temperature	- 25 ~ + 85	°C
Storage temperature	- 55 ~ + 100	°C

#### Electrical/Optical Characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Min	Typ	Max.	Unit
Forward voltage/Seg	V <sub>F</sub>	I <sub>F</sub> = 10mA	—	2.1	2.3	V
Reverse current /Seg	I <sub>R</sub>	V <sub>R</sub> = 4V	—	—	10	μA
Luminous Intensity/digit	I <sub>V</sub>	I <sub>F</sub> = 10mA	350	900	—	μcd
Peak wavelength	λ <sub>P</sub>	I <sub>F</sub> = 10mA	—	555	—	nm
Spectral line halfwidth	Δλ	I <sub>F</sub> = 10mA	—	30	—	nm

### Orange SND 3660/3667SR (GaAsP/GaP)

#### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Power dissipation/Total	1920	mW
Power dissipation/Seg	40	mW
Forward current	20	mA
Peak forward current	60*	mA
Reverse voltage	4	V
Operating temperature	- 25 ~ + 85	°C
Storage temperature	- 55 ~ + 100	°C

#### Electrical/Optical Characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Min	Typ	Max.	Unit
Forward voltage/Seg	V <sub>F</sub>	I <sub>F</sub> = 10mA	—	2.0	2.2	V
Reverse current/Seg	I <sub>R</sub>	V <sub>R</sub> = 4V	—	—	10	μA
Luminous intensity/digit	I <sub>V</sub>	I <sub>F</sub> = 10mA	700	1500	—	μcd
Peak wavelength	λ <sub>P</sub>	I <sub>F</sub> = 10mA	—	635	—	nm
Spectral line halfwidth	Δλ	I <sub>F</sub> = 10mA	—	35	—	nm

### Yellow-green SND 3660/3667UG (GaP)

#### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Power dissipation/Total	1920	mW
Power dissipation/Seg	40	mW
Forward current	20	mA
Peak forward current	60*	mA
Reverse voltage	4	V
Operating temperature	- 25 ~ + 85	°C
Storage temperature	- 55 ~ + 100	°C

#### Electrical/Optical Characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Min	Typ	Max.	Unit
Forward voltage/Seg	V <sub>F</sub>	I <sub>F</sub> = 10mA	—	2.1	2.3	V
Reverse current/Seg	I <sub>R</sub>	V <sub>R</sub> = 4V	—	—	10	μA
Luminous intensity/digit	I <sub>V</sub>	I <sub>F</sub> = 10mA	600	1500	—	μcd
Peak wavelength	λ <sub>P</sub>	I <sub>F</sub> = 10mA	—	565	—	nm
Spectral line halfwidth	Δλ	I <sub>F</sub> = 10mA	—	30	—	nm

\* Pulse Width . . . . . 1 ms  
Duty Cycle . . . . . 1/5